

CAT93C86

16 Kb Microwire Serial EEPROM

Description

The CAT93C86 is a 16 Kb Serial EEPROM memory device which is configured as either registers of 16 bits (ORG pin at V_{CC}) or 8 bits (ORG pin at GND). Each register can be written (or read) serially by using the DI (or DO) pin. The CAT93C86 is manufactured using ON Semiconductor's advanced CMOS EEPROM floating gate technology. The device is designed to endure 1,000,000 program/erase cycles and has a data retention of 100 years. The device is available in 8-pin DIP and 8-pin SOIC packages.

Features

- High Speed Operation: 3 MHz / $V_{CC} = 5\text{ V}$
- Low Power CMOS Technology
- 1.8 V to 5.5 V Operation
- Selectable x8 or x16 Memory Organization
- Self-timed Write Cycle with Auto-clear
- Hardware and Software Write Protection
- Power-up Inadvertent Write Protection
- Sequential Read
- Program Enable (PE) Pin
- 1,000,000 Program/Erase Cycles
- 100 Year Data Retention
- Industrial and Extended Temperature Ranges
- 8-lead PDIP and SOIC Packages
- These Devices are Pb-Free, Halogen Free/BFR Free, and RoHS Compliant

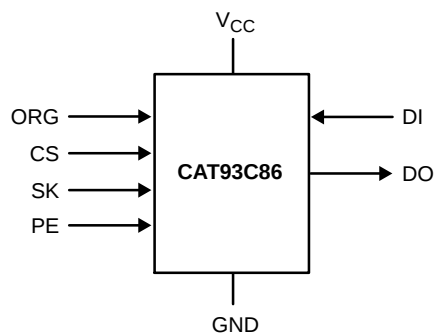


Figure 1. Functional Symbol

Note: When the ORG pin is connected to V_{CC} , the x16 organization is selected. When it is connected to ground, the x8 pin is selected. If the ORG pin is left unconnected, then an internal pull-up device will select the x16 organization.

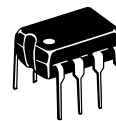


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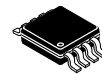
www.onsemi.com



SOIC-8
V, W SUFFIX
CASE 751BD

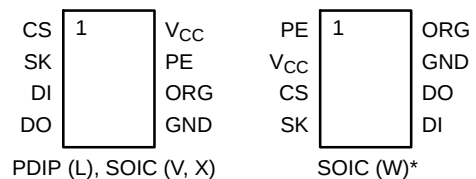


PDIP-8
L SUFFIX
CASE 646AA



SOIC-8
X SUFFIX
CASE 751BE

PIN CONFIGURATION



PIN FUNCTION

Pin Name	Function
CS	Chip Select
SK	Clock Input
DI	Serial Data Input
DO	Serial Data Output
V_{CC}	Power Supply
GND	Ground
ORG	Memory Organization
PE	Program Enable

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

* Not Recommended for New Designs

Table 1. ABSOLUTE MAXIMUM RATINGS

Parameters	Ratings	Units
Temperature Under Bias	-55 to +125	°C
Storage Temperature	-65 to +150	°C
Voltage on any Pin with Respect to Ground (Note 1)	-2.0 to +V _{CC} +2.0	V
V _{CC} with Respect to Ground	-2.0 to +7.0	V
Package Power Dissipation Capability (T _A = 25°C)	1.0	W
Lead Soldering Temperature (10 seconds)	300	°C
Output Short Circuit Current (Note 2)	100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The minimum DC input voltage is -0.5 V. During transitions, inputs may undershoot to -2.0 V for periods of less than 20 ns. Maximum DC voltage on output pins is V_{CC} +0.5 V, which may overshoot to V_{CC} +2.0 V for periods of less than 20 ns.
2. Output shorted for no more than one second. No more than one output shorted at a time.

Table 2. RELIABILITY CHARACTERISTICS

Symbol	Parameter	Reference Test Method	Min	Units
N _{END} (Note 3)	Endurance	MIL-STD-883, Test Method 1033	1,000,000	Cycles/Byte
T _{DR} (Note 3)	Data Retention	MIL-STD-883, Test Method 1008	100	Years
V _{ZAP} (Note 3)	ESD Susceptibility	MIL-STD-883, Test Method 3015	2000	V
I _{LTH} (Notes 3, 4)	Latch-Up	JEDEC Standard 17	100	mA

3. These parameters are tested initially and after a design or process change that affects the parameter.
4. Latch-up protection is provided for stresses up to 100 mA on address and data pins from -1 V to V_{CC} +1 V.

Table 3. D.C. OPERATING CHARACTERISTICS (V_{CC} = +1.8 V to +5.5 V unless otherwise specified.)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
I _{CC1}	Power Supply Current (Write)	f _{SK} = 1 MHz; V _{CC} = 5.0 V			3	mA
I _{CC2}	Power Supply Current (Read)	f _{SK} = 1 MHz; V _{CC} = 5.0 V			500	μA
I _{SB1}	Power Supply Current (Standby) (x8 Mode)	CS = 0 V ORG = GND			10	μA
I _{SB2}	Power Supply Current (Standby) (x16 Mode)	CS = 0 V ORG = Float or V _{CC}		0	10	μA
I _{LI}	Input Leakage Current	V _{IN} = 0 V to V _{CC}			1	μA
I _{LO}	Output Leakage Current (Including ORG pin)	V _{OUT} = 0 V to V _{CC} , CS = 0 V			1	μA
V _{IL1}	Input Low Voltage	4.5 V ≤ V _{CC} < 5.5 V	-0.1		0.8	V
V _{IH1}	Input High Voltage	4.5 V ≤ V _{CC} < 5.5 V	2		V _{CC} + 1	V
V _{IL2}	Input Low Voltage	1.8 V ≤ V _{CC} < 4.5 V	0		V _{CC} × 0.2	V
V _{IH2}	Input High Voltage	1.8 V ≤ V _{CC} < 4.5 V	V _{CC} × 0.7		V _{CC} + 1	V
V _{OL1}	Output Low Voltage	4.5 V ≤ V _{CC} < 5.5 V; I _{OL} = 2.1 mA			0.4	V
V _{OH1}	Output High Voltage	4.5 V ≤ V _{CC} < 5.5 V; I _{OH} = -400 μA	2.4			V
V _{OL2}	Output Low Voltage	1.8 V ≤ V _{CC} < 4.5 V; I _{OL} = 1 mA			0.2	V
V _{OH2}	Output High Voltage	1.8 V ≤ V _{CC} < 4.5 V; I _{OH} = -100 μA	V _{CC} - 0.2			V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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Table 4. PIN CAPACITANCE (Note 5)

Symbol	Test	Conditions	Min	Typ	Max	Units
C _{OUT}	Output Capacitance (DO)	V _{OUT} = 0 V			5	pF
C _{IN}	Input Capacitance (CS, SK, DI, ORG)	V _{IN} = 0 V			5	pF

Table 5. POWER-UP TIMING (Notes 5, 6)

Symbol	Parameter	Max	Units
t _{PUR}	Power-up to Read Operation	1	ms
t _{PUW}	Power-up to Write Operation	1	ms

Table 6. A.C. TEST CONDITIONS

Input Rise and Fall Times	≤ 50 ns	
Input Pulse Voltages	0.4 V to 2.4 V	4.5 V ≤ V _{CC} ≤ 5.5 V
Timing Reference Voltages	0.8 V, 2.0 V	4.5 V ≤ V _{CC} ≤ 5.5 V
Input Pulse Voltages	0.2 x V _{CC} to 0.7 x V _{CC}	1.8 V ≤ V _{CC} ≤ 4.5 V
Timing Reference Voltages	0.5 x V _{CC}	1.8 V ≤ V _{CC} ≤ 4.5 V

Table 7. A.C. CHARACTERISTICS

Symbol	Parameter	Test Conditions	V _{CC} = 1.8 V – 5.5 V		V _{CC} = 2.5 V – 5.5 V		V _{CC} = 4.5 V – 5.5 V		Units
			Min	Max	Min	Max	Min	Max	
t _{CSS}	CS Setup Time		200		100		50		ns
t _{CSH}	CS Hold Time		0		0		0		ns
t _{DIS}	DI Setup Time		200		100		50		ns
t _{DIH}	DI Hold Time		200		100		50		ns
t _{PD1}	Output Delay to 1			1		0.5		0.15	μs
t _{PD0}	Output Delay to 0	C _L = 100 pF (Note 7)		1		0.5		0.15	μs
t _{HZ} (Note 5)	Output Delay to High-Z			400		200		100	ns
t _{EW}	Program/Erase Pulse Width			5		5		5	ms
t _{CSMIN}	Minimum CS Low Time		1		0.5		0.15		μs
t _{SKHI}	Minimum SK High Time		1		0.5		0.15		μs
t _{SKLOW}	Minimum SK Low Time		1		0.5		0.15		μs
t _{SV}	Output Delay to Status Valid			1		0.5		0.1	μs
SK _{MAX}	Maximum Clock Frequency		DC	500	DC	1000	DC	3000	kHz

5. These parameters are tested initially and after a design or process change that affects the parameter.
6. t_{PUR} and t_{PUW} are the delays required from the time V_{CC} is stable until the specified operation can be initiated.
7. The input levels and timing reference points are shown in the "A.C. Test Conditions" table.

Table 8. INSTRUCTION SET

Instruction	Start Bit	Opcode	Address		Data		Comments
			x8	x16	x8	x16	
READ	1	10	A10–A0	A9–A0			Read Address AN– A0
ERASE	1	11	A10–A0	A9–A0			Clear Address AN– A0
WRITE	1	01	A10–A0	A9–A0	D7–D0	D15–D0	Write Address AN– A0
EWEN	1	00	11XXXXXXXXXX	11XXXXXXXXXX			Write Enable
EWDS	1	00	00XXXXXXXXXX	00XXXXXXXXXX			Write Disable
ERAL	1	00	10XXXXXXXXXX	10XXXXXXXXXX			Clear All Addresses
WRAL	1	00	01XXXXXXXXXX	01XXXXXXXXXX	D7–D0	D15–D0	Write All Addresses

Device Operation

The CAT93C86 is a 16,384-bit nonvolatile memory intended for use with industry standard microprocessors. The CAT93C86 can be organized as either registers of 16 bits or 8 bits. When organized as X16, seven 13-bit instructions control the reading, writing and erase operations of the device. When organized as X8, seven 14-bit instructions control the reading, writing and erase operations of the device. The CAT93C86 operates on a single power supply and will generate on chip, the high voltage required during any write operation.

Instructions, addresses, and write data are clocked into the DI pin on the rising edge of the clock (SK). The DO pin is normally in a high impedance state except when reading data from the device, or when checking the ready/busy status after a write operation.

The ready/busy status can be determined after the start of a write operation by selecting the device (CS high) and polling the DO pin; DO low indicates that the write operation is not completed, while DO high indicates that the device is ready for the next instruction. If necessary, the DO pin may be placed back into a high impedance state during chip select by shifting a dummy “1” into the DI pin. The DO pin will enter the high impedance state on the falling edge of the clock (SK). Placing the DO pin into the high impedance state is recommended in applications where the DI pin and the DO pin are to be tied together to form a common DI/O pin.

The format for all instructions sent to the device is a logical “1” start bit, a 2-bit (or 4-bit) opcode, 10-bit address (an additional bit when organized X8) and for write operations a 16-bit data field (8-bit for X8 organizations).

Note: The Write, Erase, Write all and Erase all instructions require PE = 1. If PE is left floating, 93C86 is in Program Enabled mode. For Write Enable and Write Disable instruction PE = don't care.

Read

Upon receiving a READ command and an address (clocked into the DI pin), the DO pin of the CAT93C86 will come out of the high impedance state and, after sending an initial dummy zero bit, will begin shifting out the data addressed (MSB first). The output data bits will toggle on the rising edge of the SK clock and are stable after the specified time delay (t_{PD0} or t_{PD1}).

After the initial data word has been shifted out and CS remains asserted with the SK clock continuing to toggle, the device will automatically increment to the next address and shift out the next data word in a sequential READ mode. As long as CS is continuously asserted and SK continues to toggle, the device will keep incrementing to the next address automatically until it reaches to the end of the address space, then loops back to address 0. In the sequential READ mode, only the initial data word is preceeded by a dummy zero bit. All subsequent data words will follow without a dummy zero bit.

Write

After receiving a WRITE command, address and the data, the CS (Chip Select) pin must be deselected for a minimum of t_{CSMIN} . The falling edge of CS will start the self clocking clear and data store cycle of the memory location specified in the instruction. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT93C86 can be determined by selecting the device and polling the DO pin. Since this device features Auto-Clear before write, it is NOT necessary to erase a memory location before it is written into.

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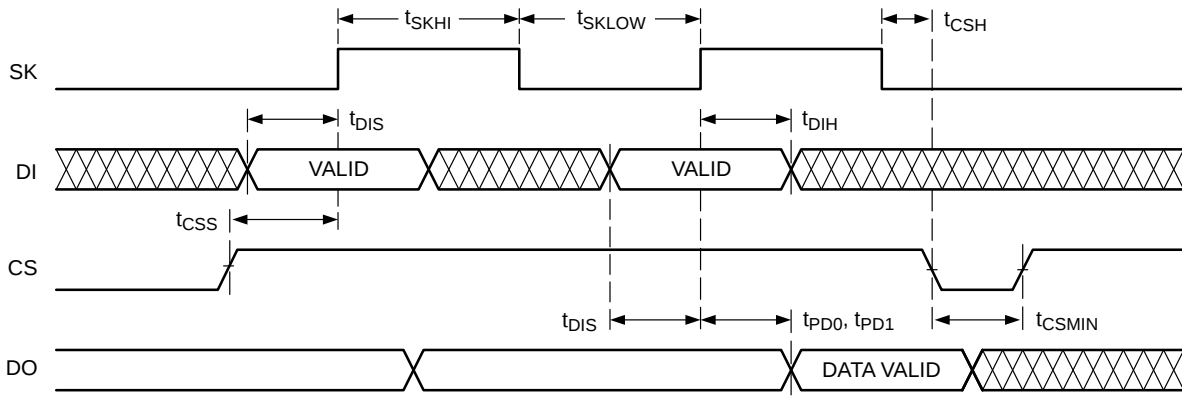


Figure 2. Synchronous Data Timing

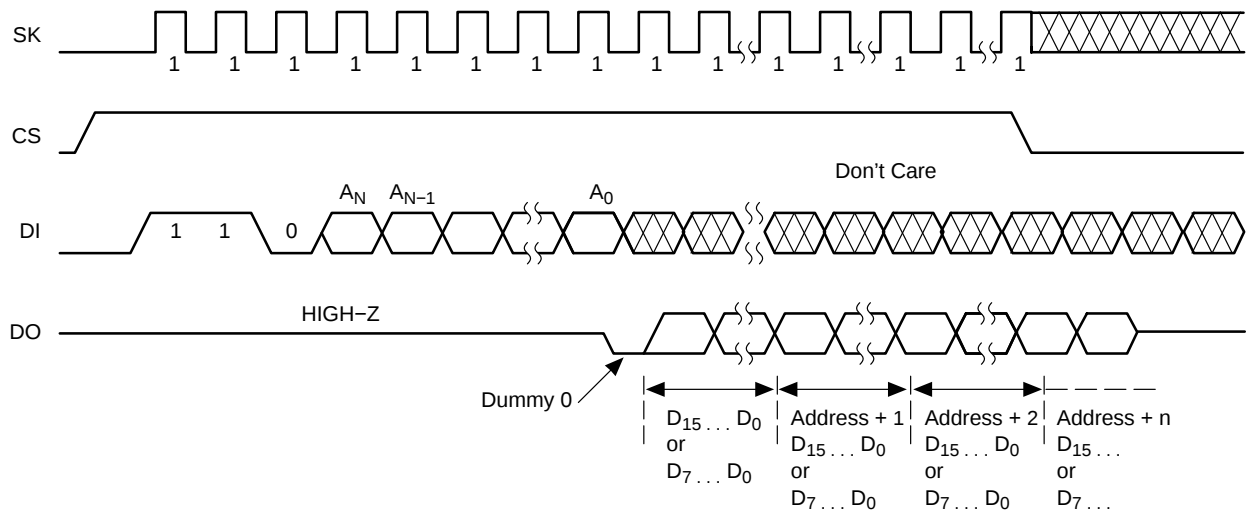


Figure 3. Read Instruction Timing

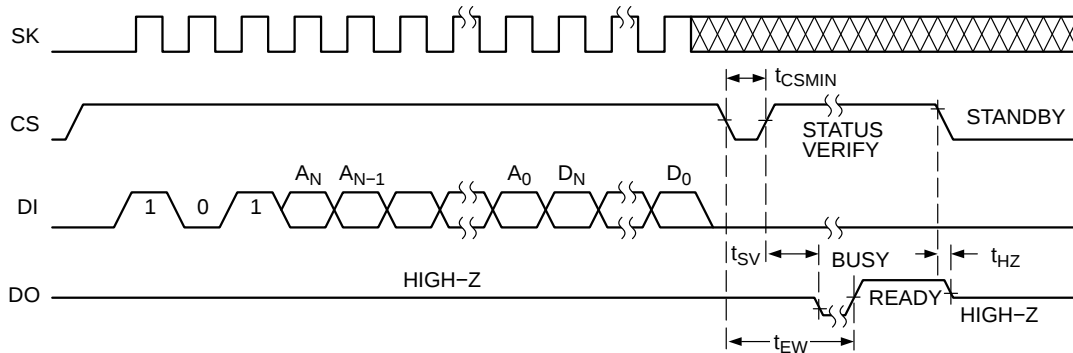


Figure 4. Write Instruction Timing

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Erase

Upon receiving an ERASE command and address, the CS (Chip Select) pin must be deasserted for a minimum of t_{CSMIN} . The falling edge of CS will start the self clocking clear cycle of the selected memory location. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT93C86 can be determined by selecting the device and polling the DO pin. Once cleared, the content of a cleared location returns to a logical "1" state.

Erase/Write Enable and Disable

The CAT93C86 powers up in the write disable state. Any writing after power-up or after an EWDS (write disable) instruction must first be preceded by the EWEN (write enable) instruction. Once the write instruction is enabled, it will remain enabled until power to the device is removed, or the EWDS instruction is sent. The EWDS instruction can be used to disable all CAT93C86 write and clear instructions, and will prevent any accidental writing or clearing of the device. Data can be read normally from the device regardless of the write enable/disable status.

Erase All

Upon receiving an ERAL command, the CS (Chip Select) pin must be deselected for a minimum of t_{CSMIN} . The falling edge of CS will start the self clocking clear cycle of all memory locations in the device. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT93C86 can be determined by selecting the device and polling the DO pin. Once cleared, the contents of all memory bits return to a logical "1" state.

Write All

Upon receiving a WRAL command and data, the CS (Chip Select) pin must be deselected for a minimum of t_{CSMIN} . The falling edge of CS will start the self clocking data write to all memory locations in the device. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT93C86 can be determined by selecting the device and polling the DO pin. It is not necessary for all memory locations to be cleared before the WRAL command is executed.

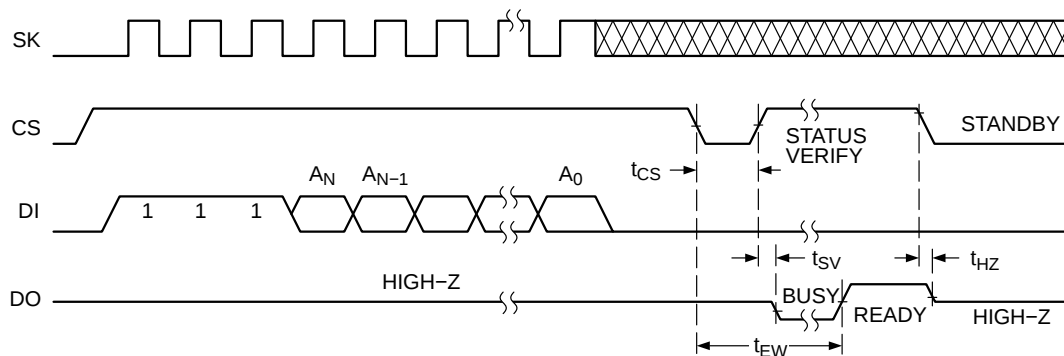
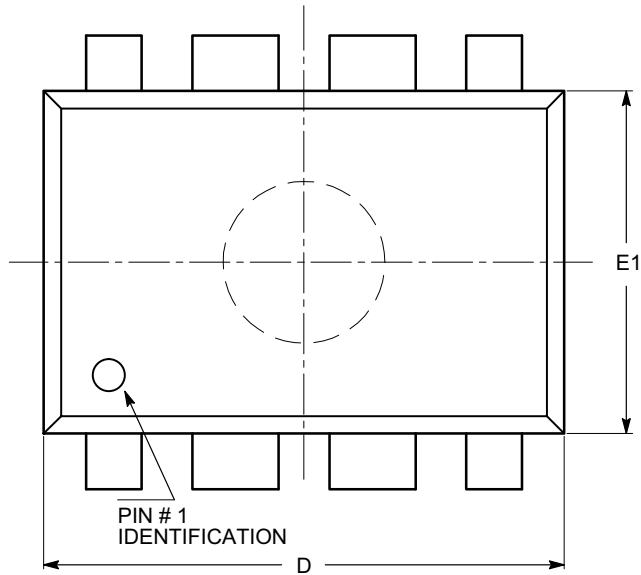


Figure 5. Erase Instruction Timing

CAT93C86

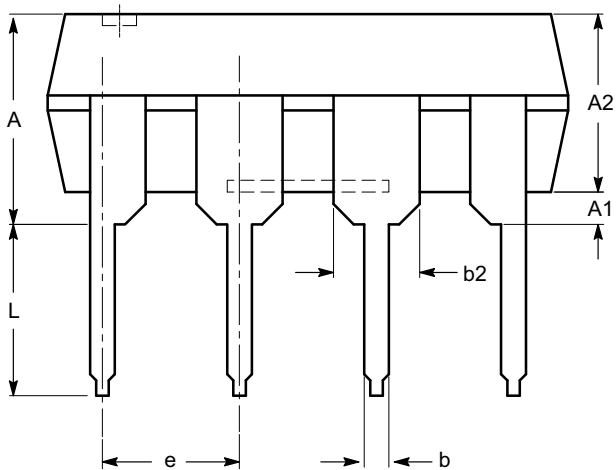
PACKAGE DIMENSIONS

PDIP-8, 300 mils
CASE 646AA-01
ISSUE A

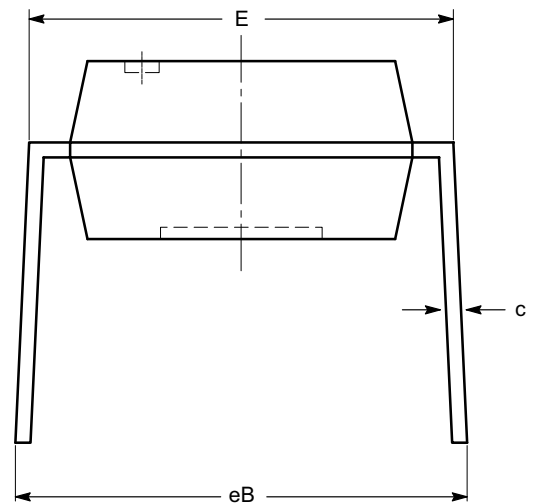


SYMBOL	MIN	NOM	MAX
A			5.33
A1	0.38		
A2	2.92	3.30	4.95
b	0.36	0.46	0.56
b2	1.14	1.52	1.78
c	0.20	0.25	0.36
D	9.02	9.27	10.16
E	7.62	7.87	8.25
E1	6.10	6.35	7.11
e	2.54 BSC		
eB	7.87		10.92
L	2.92	3.30	3.80

TOP VIEW



SIDE VIEW



END VIEW

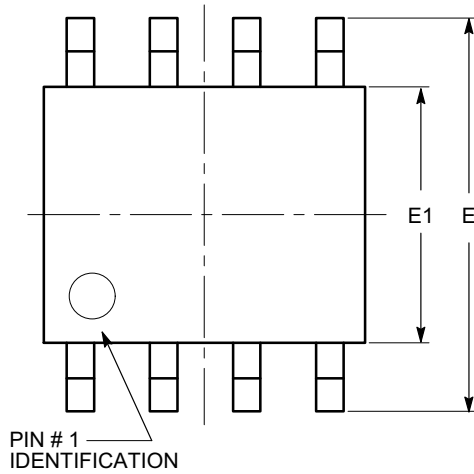
Notes:

- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC MS-001.

CAT93C86

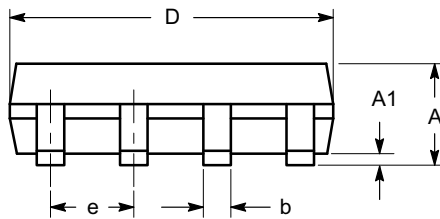
PACKAGE DIMENSIONS

SOIC 8, 150 mils
CASE 751BD-01
ISSUE O

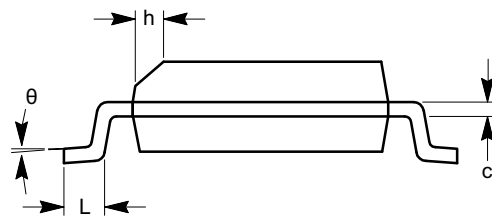


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
c	0.19		0.25
D	4.80		5.00
E	5.80		6.20
E1	3.80		4.00
e	1.27 BSC		
h	0.25		0.50
L	0.40		1.27
θ	0°		8°



SIDE VIEW



END VIEW

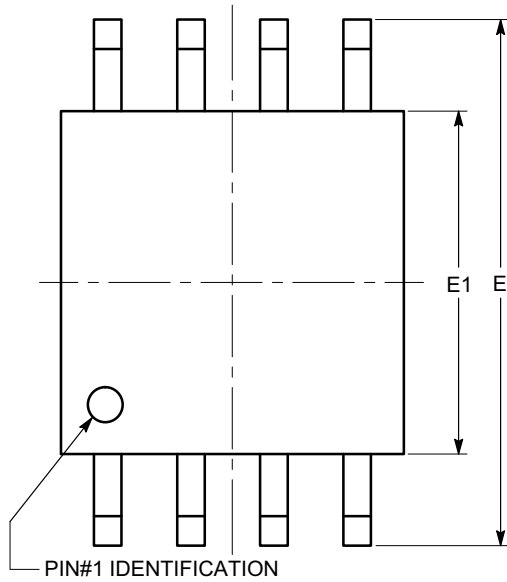
Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-012.

CAT93C86

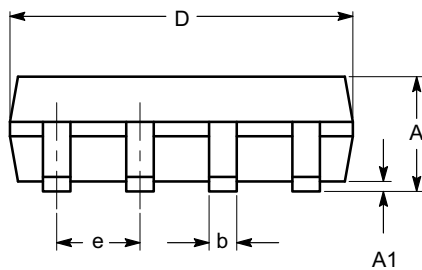
PACKAGE DIMENSIONS

SOIC-8, 208 mils
CASE 751BE-01
ISSUE O

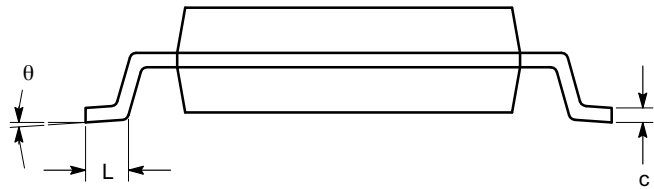


TOP VIEW

SYMBOL	MIN	NOM	MAX
A			2.03
A1	0.05		0.25
b	0.36		0.48
c	0.19		0.25
D	5.13		5.33
E	7.75		8.26
E1	5.13		5.38
e	1.27 BSC		
L	0.51		0.76
θ	0°		8°



SIDE VIEW



END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with EIAJ EDR-7320.

CAT93C86

ORDERING INFORMATION

OPN	Specific Device Marking*	Pkg Type	Temperature Range	Lead Finish	Shipping
CAT93C86LI-G	93C86D	PDIP-8	I = Industrial (-40°C to +85°C)	NiPdAu	Tube, 50 Units / Tube
CAT93C86VI-G	93C86D	SOIC-8, JEDEC	I = Industrial (-40°C to +85°C)	NiPdAu	Tube, 100 Units / Tube
CAT93C86VI-GT3	93C86D	SOIC-8, JEDEC	I = Industrial (-40°C to +85°C)	NiPdAu	Tape & Reel, 3000 Units / Reel
CAT93C86WI-GT3 (Note 10)	93C86D	SOIC-8, JEDEC	I = Industrial (-40°C to +85°C)	NiPdAu	Tape & Reel, 3000 Units / Reel
CAT93C86XI-T2	93C86D	SOIC-8, EIAJ	I = Industrial (-40°C to +85°C)	Matte-Tin	Tape & Reel, 2000 Units / Reel

*Marking for new product Revision D.

8. All packages are RoHS-compliant (Lead-free, Halogen-free).

9. The standard lead finish is NiPdAu.

10. Not recommended for new designs.

11. For additional package and temperature options, please contact your nearest ON Semiconductor Sales office.

12. For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

13. For detailed information and a breakdown of device nomenclature and numbering systems, please see the ON Semiconductor Device Nomenclature document, TND310/D, available at www.onsemi.com

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